

**2N65-CBS**

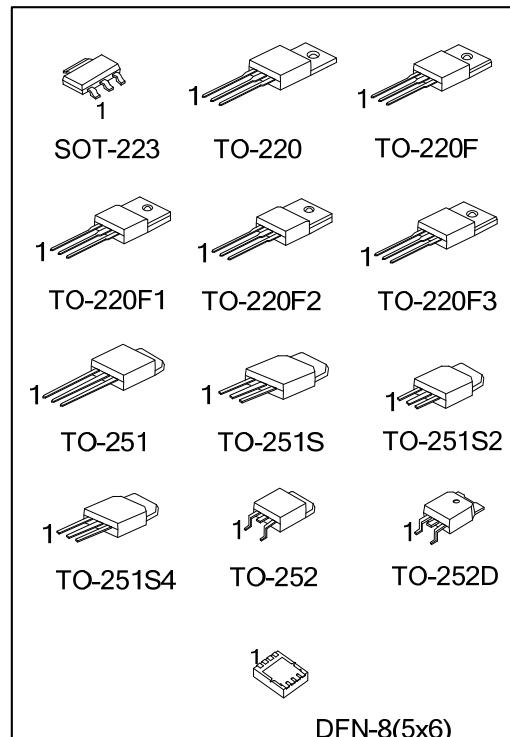
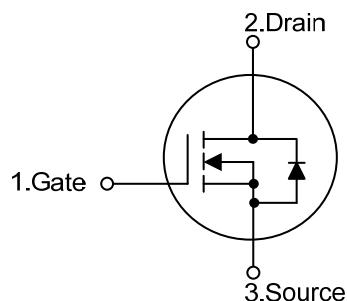
Preliminary

**Power MOSFET****2.0A, 650V N-CHANNEL  
POWER MOSFET****■ DESCRIPTION**

The UTC **2N65-CBS** is a high voltage power MOSFET and is designed to have better characteristics, such as fast switching time, low gate charge, low on-state resistance and have a high rugged avalanche characteristics. This power MOSFET is usually used at high speed switching applications in power supplies, PWM motor controls, high efficient DC to DC converters and bridge circuits.

**■ FEATURES**

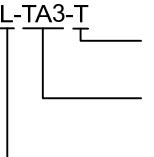
- \*  $R_{DS(ON)} < 9.5\Omega$  @  $V_{GS} = 10V$ ,  $I_D = 1.0A$
- \* Fast switching capability
- \* Avalanche energy specified
- \* Improved dv/dt capability, high ruggedness

**■ SYMBOL**

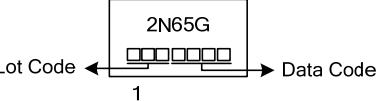
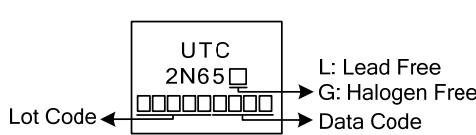
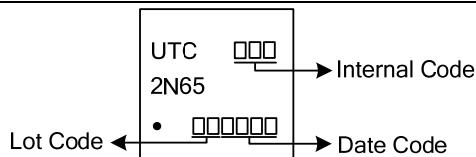
### ■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment								Packing
Lead Free	Halogen Free		1	2	3	4	5	6	7	8	
-	2N65G-AA3-R	SOT-223	G	D	S	-	-	-	-	-	Tape Reel
2N65L-TA3-T	2N65G-TA3-T	TO-220	G	D	S	-	-	-	-	-	Tube
2N65L-TF3-T	2N65G-TF3-T	TO-220F	G	D	S	-	-	-	-	-	Tube
2N65L-TF1-T	2N65G-TF1-T	TO-220F1	G	D	S	-	-	-	-	-	Tube
2N65L-TF2-T	2N65G-TF2-T	TO-220F2	G	D	S	-	-	-	-	-	Tube
2N65L-TF3T-T	2N65G-TF3T-T	TO-220F3	G	D	S	-	-	-	-	-	Tube
2N65L-TM3-T	2N65G-TM3-T	TO-251	G	D	S	-	-	-	-	-	Tube
2N65L-TMS-T	2N65G-TMS-T	TO-251S	G	D	S	-	-	-	-	-	Tube
2N65L-TMS2-T	2N65G-TMS2-T	TO-251S2	G	D	S	-	-	-	-	-	Tube
2N65L-TMS4-T	2N65G-TMS4-T	TO-251S4	G	D	S	-	-	-	-	-	Tube
2N65L-TN3-R	2N65G-TN3-R	TO-252	G	D	S	-	-	-	-	-	Tape Reel
2N65L-TND-R	2N65G-TND-R	TO-252D	G	D	S	-	-	-	-	-	Tape Reel
-	2N65G-K08-5060-R	DFN-8(5x6)	S	S	S	G	D	D	D	D	Tape Reel

Note: Pin Assignment: G: Gate D: Drain S: Source

 (1)Packing Type (2)Package Type (3)Green Package	(1) T: Tube, R: Tape Reel (2) AA3: SOT-223, TA3: TO-220, TF3: TO-220F, TF1: TO-220F1, TF1: TO-220F2, TF3: TO-220F3, TM3: TO-251, TMS: TO-251S, TMS2: TO-251S2, TMS4: TO-251S4, TN3: TO-252, TND: TO-252D K08-5060: DFN-8(5x6) (3) L: Lead Free, G: Halogen Free and Lead Free
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### ■ MARKING

PACKAGE	MARKING
SOT-223	 Lot Code ← Data Code →
TO-220 / TO-220F TO-220F1 / TO-220F2 TO-220F3 / TO-251 TO-251S / TO-251S2 TO-251S4 / TO-252 TO-252D	 Lot Code ← Data Code → L: Lead Free G: Halogen Free
DFN-8(5x6)	 Internal Code → Date Code ←

■ ABSOLUTE MAXIMUM RATINGS ( $T_c=25^\circ\text{C}$ , unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Drain-Source Voltage		$V_{DSS}$	650	V
Gate-Source Voltage		$V_{GSS}$	$\pm 30$	V
Avalanche Current (Note 2)		$I_{AR}$	1.6	A
Drain Current	Continuous	$I_D$	2.0	A
	Pulsed (Note 2)	$I_{DM}$	8.0	A
Avalanche Energy	Single Pulsed (Note 3)	$E_{AS}$	13	mJ
Peak Diode Recovery dv/dt (Note 4)		dv/dt	4.2	V/ns
Power Dissipation	SOT-223	$P_D$	44	W
	TO-220		54	W
	TO-220F/TO-220F1		23	W
	TO-220F3		24	W
	TO-220F2		44	W
	TO-251/TO-251S		22	W
	TO-251S2/TO-251S4		+150	°C
	TO-252/TO-252D		-55 ~ +150	°C
DFN-8(5x6)				
Junction Temperature	$T_J$			
Storage Temperature	$T_{STG}$			

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged.

Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating : Pulse width limited by maximum junction temperature.

3.  $L=10\text{mH}$ ,  $I_{AS}=1.6\text{A}$ ,  $V_{DD}=50\text{V}$ ,  $R_G=25\ \Omega$ , Starting  $T_J = 25^\circ\text{C}$

4.  $I_{SD} \leq 2.0\text{A}$ ,  $di/dt \leq 100\text{A}/\mu\text{s}$ ,  $V_{DD} \leq BV_{DSS}$ , Starting  $T_J = 25^\circ\text{C}$

## ■ THERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Ambient	SOT-223	$\theta_{JA}$	150	°C/W
	TO-220/TO-220F		62.5	°C/W
	TO-220F1/ TO-220F2		100	°C/W
	TO-220F3		75	°C/W
	TO-251/TO-251S		2.84	°C/W
	TO-251S2/TO-251S4		2.32	°C/W
	TO-252/TO-252D		5.4	°C/W
	DFN-8(5x6)		5.2	°C/W
Junction to Case	SOT-223	$\theta_{JC}$	2.84	°C/W
	TO-220		2.32	°C/W
	TO-220F/TO-220F1		5.2	°C/W
	TO-220F3		2.84	°C/W
	TO-220F2		5.7	°C/W
	TO-251/TO-251S			
	TO-251S2/TO-251S4			
	TO-252/TO-252D			
DFN-8(5x6)				

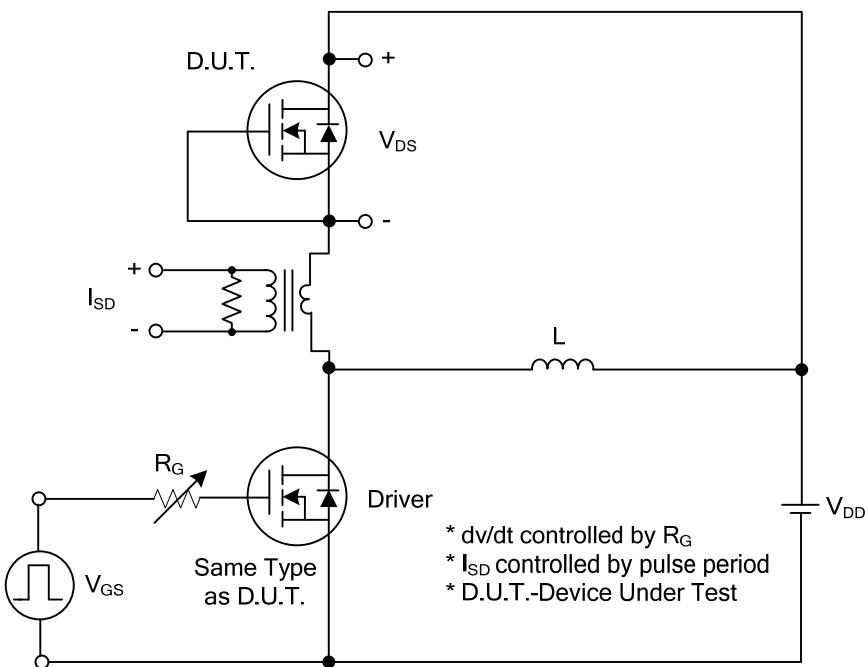
■ ELECTRICAL CHARACTERISTICS ( $T_c = 25^\circ\text{C}$ , unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
<b>OFF CHARACTERISTICS</b>						
Drain-Source Breakdown Voltage	$\text{BV}_{\text{DSS}}$	$V_{\text{GS}} = 0\text{V}, I_{\text{D}} = 250\mu\text{A}$	650			V
Drain-Source Leakage Current	$I_{\text{DSS}}$	$V_{\text{DS}} = 650\text{V}, V_{\text{GS}} = 0\text{V}$		1		$\mu\text{A}$
Gate-Source Leakage Current	Forward	$V_{\text{GS}} = 30\text{V}, V_{\text{DS}} = 0\text{V}$		100		nA
	Reverse	$V_{\text{GS}} = -30\text{V}, V_{\text{DS}} = 0\text{V}$		-100		nA
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	$V_{\text{GS(TH)}}$	$V_{\text{DS}} = V_{\text{GS}}, I_{\text{D}} = 250\mu\text{A}$	2.0		4.0	V
Static Drain-Source On-State Resistance	$R_{\text{DS(ON)}}$	$V_{\text{GS}} = 10\text{V}, I_{\text{D}} = 1.0\text{A}$			9.5	$\Omega$
<b>DYNAMIC CHARACTERISTICS</b>						
Input Capacitance	$C_{\text{ISS}}$	$V_{\text{DS}} = 25\text{V}, V_{\text{GS}} = 0\text{V}, f = 1\text{MHz}$		158		pF
Output Capacitance	$C_{\text{OSS}}$			19		pF
Reverse Transfer Capacitance	$C_{\text{RSS}}$			3.5		pF
<b>SWITCHING CHARACTERISTICS</b>						
Total Gate Charge	$Q_G$	$V_{\text{DS}} = 50\text{V}, V_{\text{GS}} = 10\text{V}, I_{\text{D}} = 1.3\text{A}$ $I_G = 100\mu\text{A}$ (Note 1, 2)		16		nC
Gate-Source Charge	$Q_{\text{GS}}$			1.8		nC
Gate-Drain Charge	$Q_{\text{GD}}$			1.6		nC
Turn-On Delay Time	$t_{\text{D(ON)}}$			41		ns
Turn-On Rise Time	$t_R$			2		ns
Turn-Off Delay Time	$t_{\text{D(OFF)}}$			86		ns
Turn-Off Fall Time	$t_F$			31		ns
<b>DRAIN-SOURCE DIODE CHARACTERISTICS</b>						
Continuous Drain-Source Current	$I_{\text{SD}}$				2.0	A
Pulsed Drain-Source Current	$I_{\text{SM}}$				8.0	A
Drain-Source Diode Forward Voltage	$V_{\text{SD}}$	$V_{\text{GS}} = 0\text{V}, I_{\text{SD}} = 2.0\text{A}$			1.4	V
Body Diode Reverse Recovery Time	$t_{\text{rr}}$	$V_{\text{GS}} = 0\text{V}, I_{\text{SD}} = 2.0\text{A}, \frac{dI_F}{dt} = 100\text{A}/\mu\text{s}$		370		ns
Body Diode Reverse Recovery Charge	$Q_{\text{rr}}$			0.67		$\mu\text{C}$

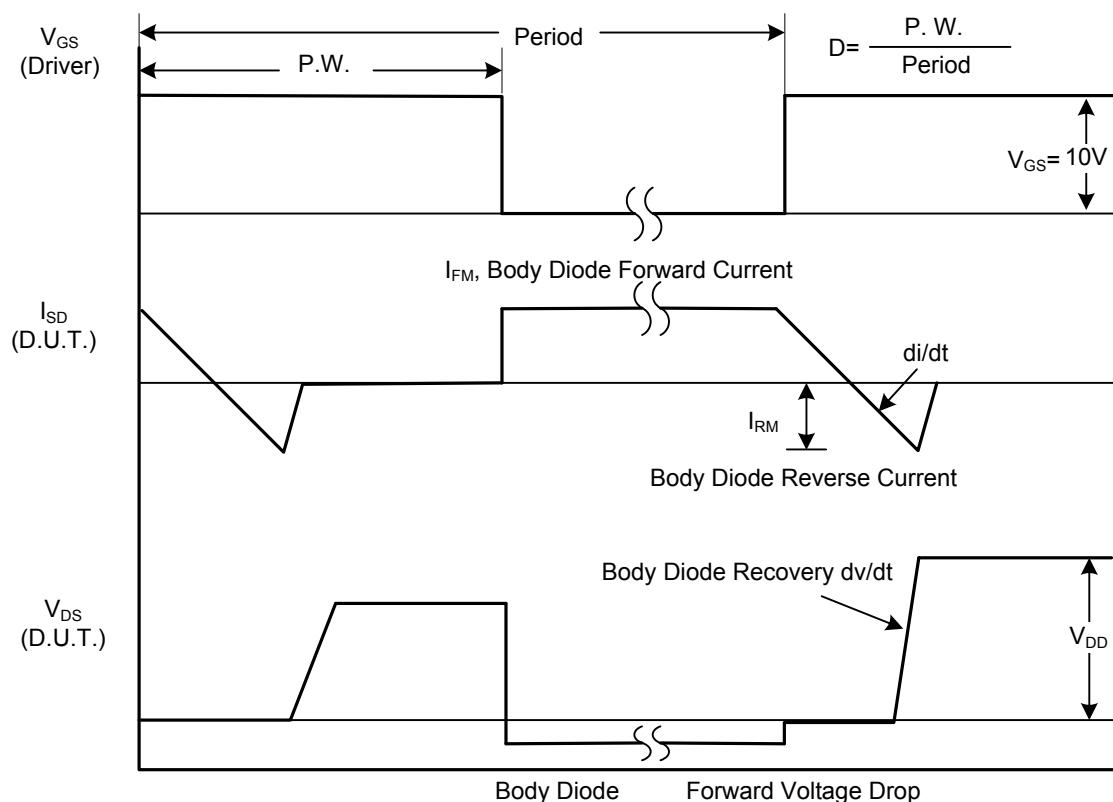
Notes: 1. Pulse Test: Pulse width  $\leq 300\mu\text{s}$ , Duty cycle  $\leq 2\%$ .

2. Essentially independent of operating temperature.

■ TEST CIRCUITS AND WAVEFORMS

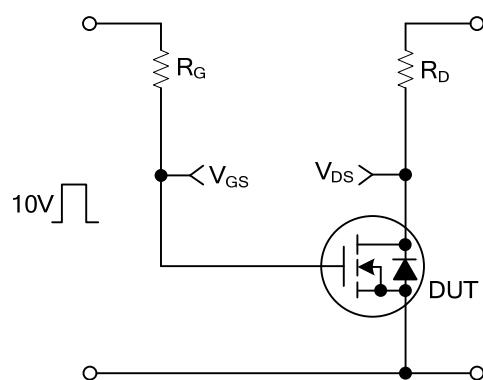


**Peak Diode Recovery dv/dt Test Circuit**

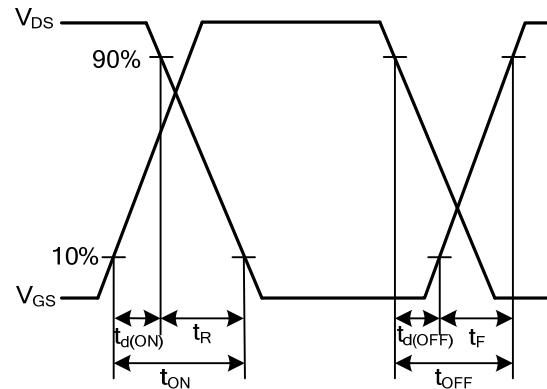


**Peak Diode Recovery dv/dt Waveforms**

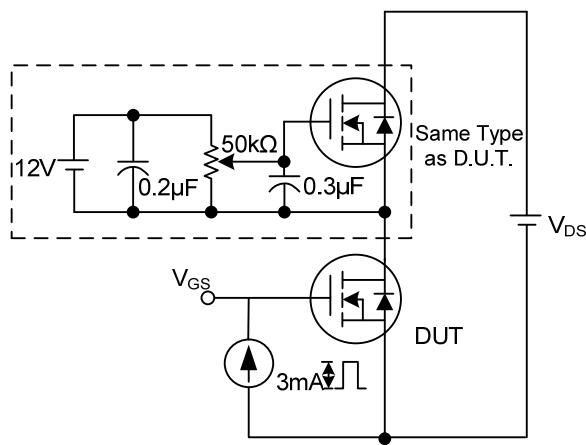
■ TEST CIRCUITS AND WAVEFORMS (Cont.)



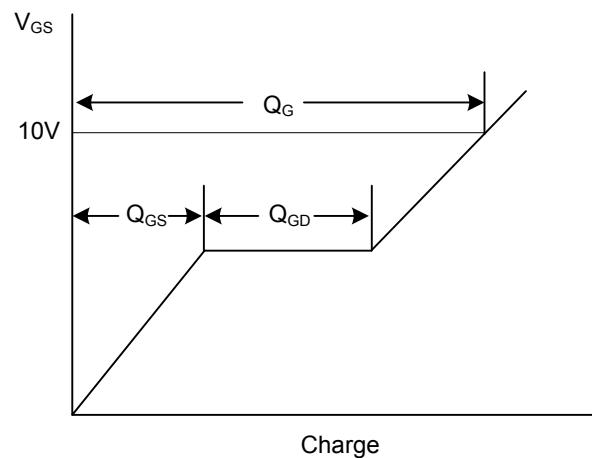
itching Test Circuit



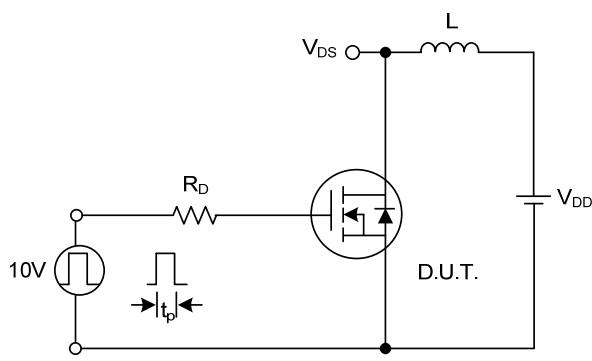
Switching Waveforms



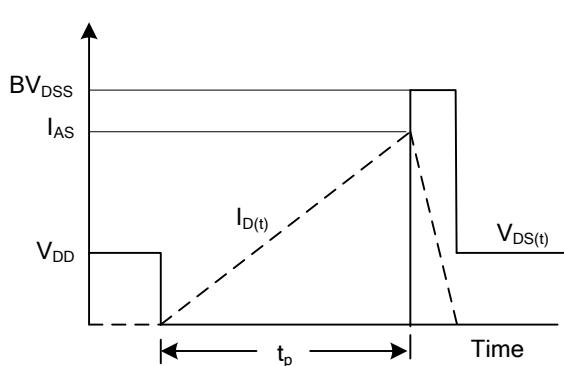
Gate Charge Test Circuit



Gate Charge Waveform



Unclamped Inductive Switching Test Circuit



Unclamped Inductive Switching Waveforms

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